# NSN 5961-00-230-8543

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Inclosure Material:

Metal

**Overall Length:** 

0.460 inches

Mounting Facility Quantity:

1

## Internal Configuration:

Junction contact

**Mounting Method:** 

Threaded stud

**Features Provided:** 

Hermetically sealed case

**Overall Width Across Flats:** 

0.687 inches

Thread Size:

0.250 inches

Semiconductor Material:

Silicon

## Voltage Rating In Volts Per Characteristic:

100.0 breakdown voltage, collector-to-base, emitter open and 80.0 breakdown voltage, collector-to-emitter, base open and 8.0

breakdown voltage, emitter-to-base, collector open

# **Current Rating Per Characteristic:**

Between 4.00 amperes source cutoff current and 10.00 amperes source cutoff current

## Power Rating Per Characteristic:

50.0 watts small-signal input power, common-collector

## Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

#### **Special Features:**

Junction pattern arrangement: npn

## Thread Series Designator:

Unf

## **Terminal Type And Quantity:**

3 tab, solder lug

Shelf Life:

N/a

## Unit Of Measure:

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## Demilitarization:

No

Fiig:

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